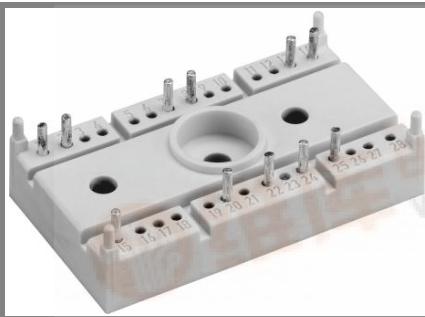


SK 40 DH



SEMITOP® 3

Half Controlled Bridge Rectifier

SK 40 DH

Preliminary Data

Features

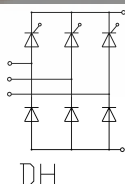
- Compact design
- One screw mounting
- Heat transfer and insulation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

Typical Applications

- Soft starters
- Light control
- Temperature control
- Motor control

V_{RSM} V	V_{RRM}, V_{DRM} V	$I_D = 42$ A (full conduction) ($T_s = 80$ °C)
900	800	SK 40 DH 08
1300	1200	SK 40 DH 12
1700	1600	SK 40 DH 16

Symbol	Conditions	Values	Units
I_D	$T_s = 80$ °C	42	A
I_{FSM} / I_{TSM}	$T_{vj} = 25$ °C; 10 ms $T_{vj} = 125$ °C; 10 ms	320 280	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms $T_{vj} = 125$ °C; 8,3...10 ms	510 390	A²s
V_T	$T_{vj} = 25$ °C; 75A	max. 2,45	V
$V_{T(TO)}$	$T_{vj} = 125$ °C;	1,1	V
r_T	$T_{vj} = 125$ °C	20	mΩ
I_{DD}, I_{RD}	$T_{vj} = 125$ °C; $V_{DD} = V_{DRM}, V_{RD} = V_{RRM}$	max. 8	mA
t_{gd}	$T_{vj} =$ °C; $I_G =$ A; $di_G/dt =$ A/μs		μs
t_{gr}	$V_D = \cdot V_{DRM}$		μs
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C; d.c.	max. 1000	V/μs
$(di/dt)_{cr}$	$T_{vj} = 125$ °C; d.c.; $f = 50...60$ Hz	max. 50	A/μs
t_q	$T_{vj} = 125$ °C; d.c.; typ.	120	μs
I_H	$T_{vj} = 25$ °C; d.c.; typ. / max.	80 / 150	mA
I_L	$T_{vj} = 25$ °C; d.c.; $R_G = 33$ Ω	150 / 300	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 2	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 100	mA
V_{GD}	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 125$ °C; d.c.	max. 3	mA
$R_{th(j-s)}$	Per thyristor Per diode	1,7 1,7	K/W
T_{solder}	Terminals, 10s	260	°C
T_{vj}	Diodes	-40...+150	°C
T_{vj}			°C
T_{stg}		-40...+125	°C
T_{vj}	Thyristors	-40...+125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 (2500)	V
M_s	Mounting torque to heatsink	2,5	Nm
a			m/s²
m	weight	30	g
Case	SEMITOP® 3	T 39	



DH



SK 40 DH

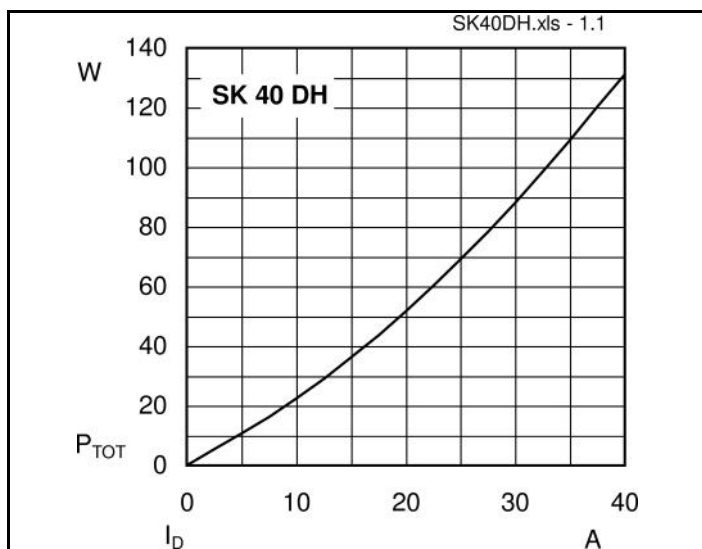


Fig. 1 Power dissipation vs. output current

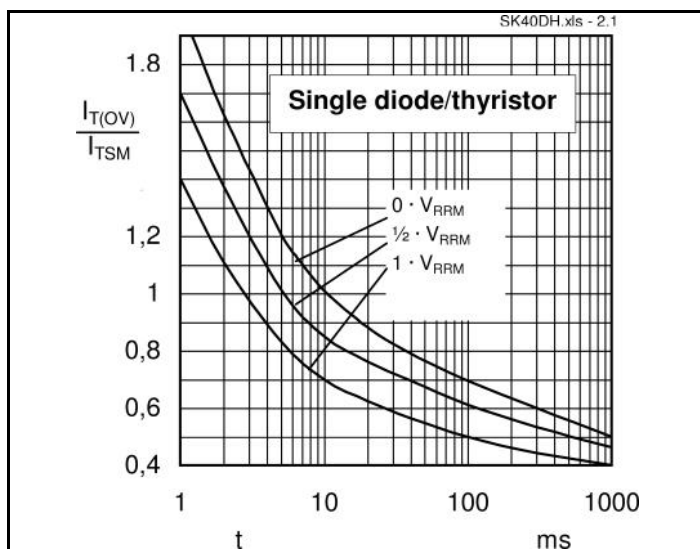


Fig. 2 Surge overload current vs. time

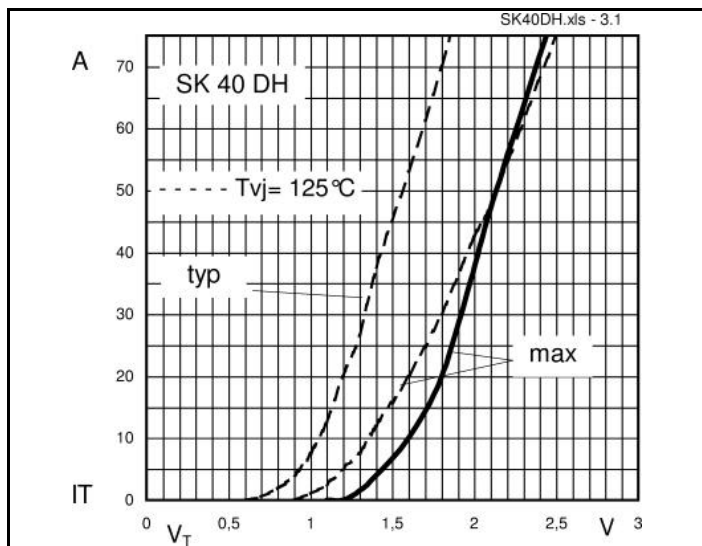


Fig. 3.1 Forward characteristics of single thyristor

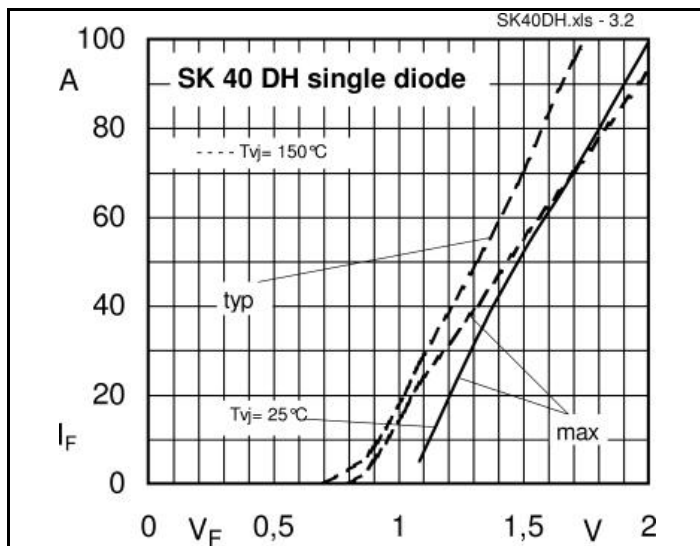


Fig. 3.2 Forward characteristics of single diode

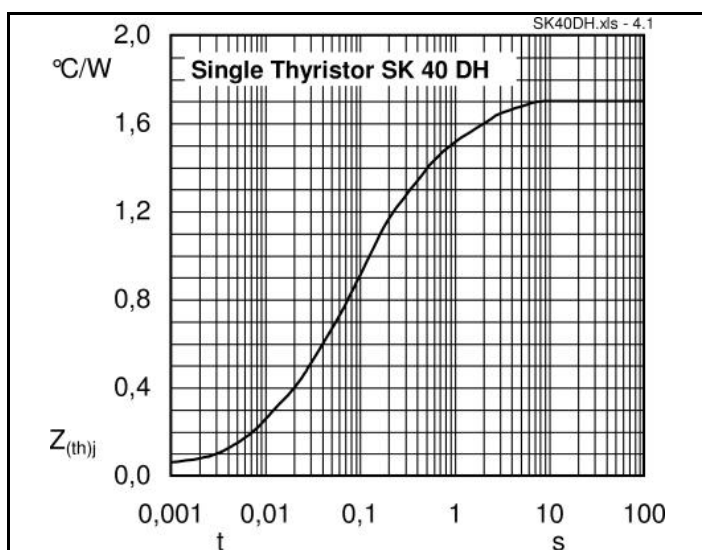


Fig. 4.1 Transient thermal impedance vs. time for single thyristor

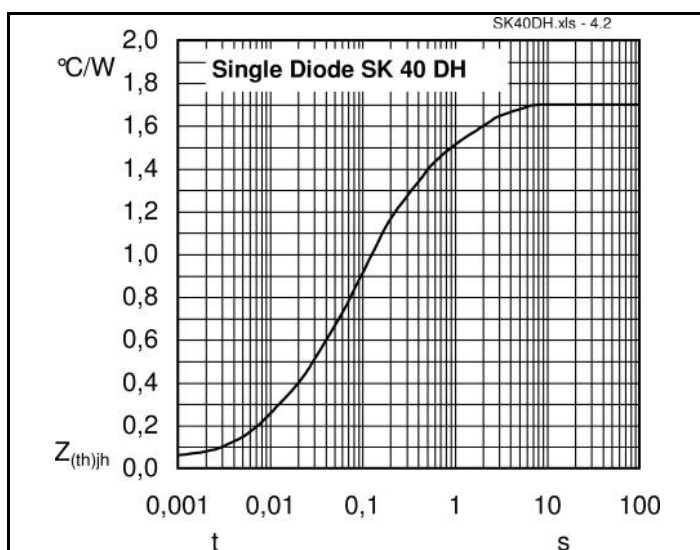


Fig. 4.2 Transient thermal impedance vs. time for single diode

SK 40 DH

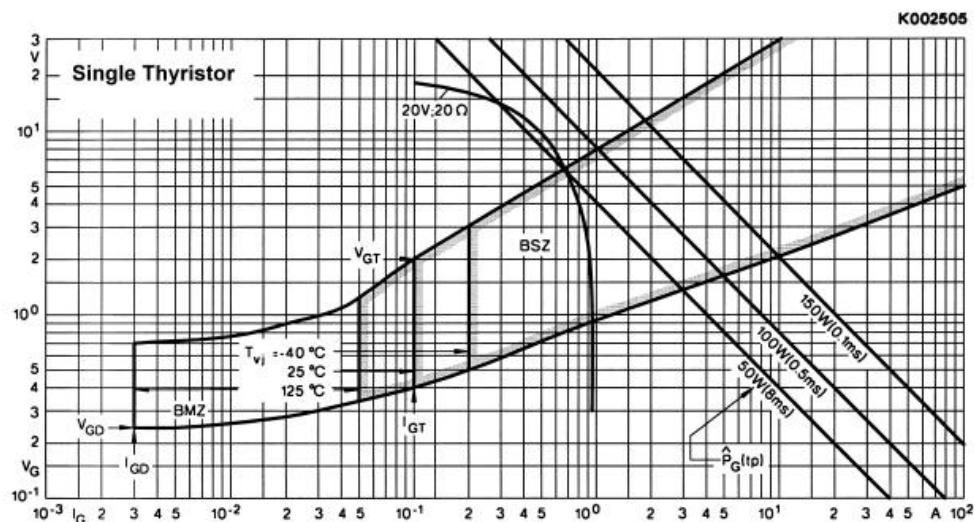
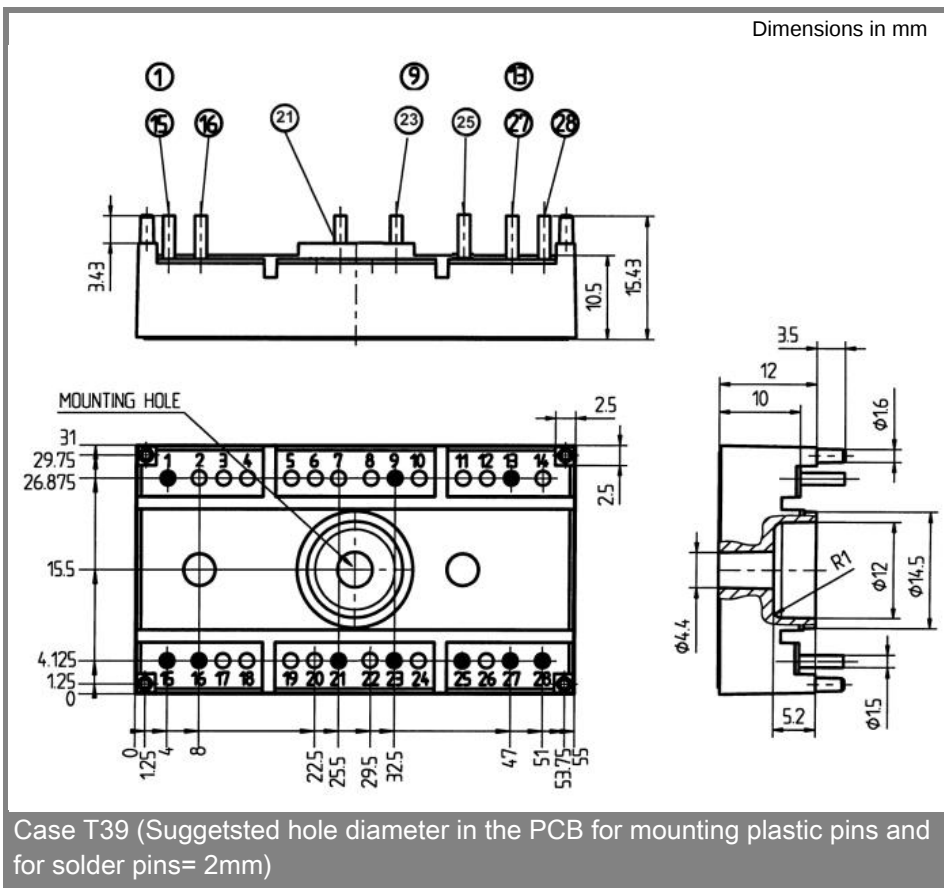
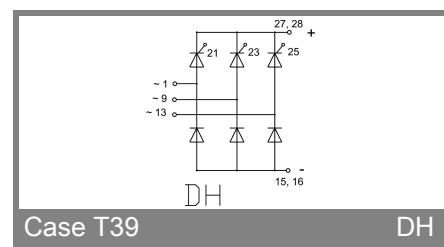


Fig. 5 Gate trigger characteristics



Case T39 (Suggested hole diameter in the PCB for mounting plastic pins and for solder pins= 2mm)



Case T39

DH

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